D ynam ical properties of a strongly correlated model for quarter—lled layered organic molecular crystals

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The dynam ical properties of an extended Hubbard model, which is relevant to quarter—led layered organic molecular crystals, are analyzed. We have computed the dynam ical charge correlation function, spectral density, and optical conductivity using Lanczos diagonalization and large-N techniques. As the ratio of the nearest-neighbour Coulomb repulsion, V, to the hopping integral, t, increases there is a transition from a metallic phase to a charge ordered phase. Dynamical properties close to the ordering transition are found to dier from the ones expected in a conventional metal. Large-N calculations display an enhancement of spectral weight at low frequencies as the system is driven closer to the charge ordering transition in agreement with Lanczos calculations. As V is increased the charge correlation function displays a plasm on-like mode which, for wavevectors close to (;), increases in amplitude and softens as the charge ordering transition is approached. We propose that inelastic X-ray scattering be used to detect this mode. Large-N calculations predict superconductivity with d_{xy} symmetry close to the ordering transition. We not that this is consistent with Lanczos diagonalisation calculations, on lattices of 20 sites, which not that the binding energy of two holes become a negative close to the charge ordering transition.

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I. IN TRODUCTION

The competition between charge ordered, metallic, and superconducting phases is relevant to a broad range of strongly correlated electron materials. For example, in the vanadium bronze $-Na_{0.33}V_2O_5$, superconductivity appears close to a charge ordered phase under an applied external pressure¹. The appearance of a pseudogap in oxygenated samples of $Nd_{1:85}$ $Ce_{0:15}$ Cu_{4+y} has been suggested to be due to charge ordering². Quarter-led layered organic materials such as the BEDT-TTF family of organic molecular crystals³ with the and 00 molecular stacking patterns also display a subtle competition of metallic, insulating, charge ordered, and superconducting phases⁴. Superconductivity in organic compounds is usually found in close proximity to ordered insulating phases³. For example, $-(BEDT-TTF)_2CuN(CN)_2Cl$ is an antiferrom agnetic Mott insulator which becomes superconducting under pressure⁵. Superconducting $-(ET)_2I_3$ and $-(BEDT-TTF)_3Cl_2(H_2O)_2$ are close to charge ordered phases⁶. Superconductivity occurs in the quasi-one-dimensional Bechgaard salts, TM TSF₂X, when a spin-density wave is suppressed. It is then important to understand the connection of the superconducting state to the nearby ordered phases and analyze the elect of the uctuations associated with the ordering transition on the normal metallic phase.

Several anom alous properties have been observed close to the charge ordering transition in quarter—lled organic conductors: (i) Suppression of D rude weight and enhancement of optical spectra at low frequencies at about 500–1000 cm ¹ in metallic [7,8] [©] [9] and —salts [10] at low temperatures. (ii) The temperature dependence of the resistivity may be different from Fermi liquid behavior, in particular, the resistivity can increase as the temperature is decreased just before becoming superconducting (see the Table in Ref. 6). Previously we have explored, using slave bosons, the possibility of superconductivity⁶ and the metal-insulator transition¹¹ in the quarter—lled extended Hubbard model. Here, we concentrate on the dynamical properties in the metallic phase close to the charge ordering transition. We not that due to the scattering of electrons from charge uctuations with (;) wavevector, dynamical and transport properties display behavior different from that expected in a typical metal. For instance, a strong suppression of quasiparticle weight as well as enhancement of spectral weight at low but nite frequencies takes place as the charge ordering transition is approached from the metallic side. Also we examine the possibility of superconductivity mediated by short range charge uctuations close to the transition using both Lanczos diagonalisation and large-N approaches.

We not that superconductivity with d_{xy} symmetry is possible close to the charge ordering transition. We note that the present analysis is similar in spirit to those that aim to understand the elect of spin uctuations on the metallic phase and the possibility of superconductivity mediated by them ¹² in high-T_c compounds, -(BEDT-TTF)₂X [13], heavy fermions, ¹⁴ and ruthenates ¹⁵.

The paper is organized as follows. In Section II, we introduce an extended Hubbard model used to describe the electronic properties of quarter—led layered molecular crystals. We also review the path integral formalism written in terms of Hubbard operators and the large-N expansion introduced to compute electronic properties of the model. In Section III, we show results for the dynamical charge correlation function, spectral density, and optical conductivity computed with Lanczos diagonalisation comparing them with large-N results. In Section IV we discuss our results contrasting them with available experimental data on the quarter—led organics. Section V is devoted to the possibility of having superconductivity in the model.

II. DYNAM ICAL PROPERTIES IN THE U-INFINITE LIM IT: LARGE-N APPROACH

We consider an extended Hubbard model at one-quarter lling on a square lattice. This has been argued to be the simplest model needed to understand the electronic properties of the layered molecular crystals with the and molecular arrangements within each layer. The Hamiltonian is

where U and V are the on-site and the nearest-neighbors C oulom b repulsion, respectively. c_i^V creates an electron of spin at site i. In the lim it U V the ground state is insulating with a checkerboard charge ordered pattern ⁴. For U! 1 and V = 0, the system is expected to be metallic as it is quarter-led. Evaluation of the D rude weight by Lanczos techniques suggests a metal-insulator transition takes place at a nite value of V_c 22t for a su ciently large value ¹¹ of U = 10t.

We now introduce the Hubbard operators

$$X_{i}^{0} = (1 \quad c_{i}^{y} c_{i}) c_{i}; \quad X_{i}^{0} = (X_{i}^{0})^{y}; \quad X_{i}^{0} = c_{i}^{y} c_{i} c_{i}$$
 (2)

The veHubbard $\hat{X_i}$ -operators X_i^0 and X_i^{00} are boson-like and the fourHubbard \hat{X} -operators X_i^0 and X_i^0 are ferm ion-like. The names ferm ion-like and boson-like come from the fact that Hubbard operators do not verify the usual ferm ionic and bosonic commutation relations 16.

In the U—in nite $\lim_{t\to\infty} it$, the Hamiltonian (1) (t U W model W ith U = 0) can be W ritten in terms of Hubbard operators as

where is the chemical potential. The Hubbard operators in this limit satisfy the completeness condition

$$X_{i}^{00} + X_{i} = 1;$$
 (4)

which is equivalent to imposing that "double occupancy" at each site is forbidden.

There are two main diculties in the calculation of physical quantities using Ham iltonian (1): the complicated commutation rules of the Hubbard operators of and that there is no small parameter in the model. A popular method for handling the former diculty is to use slave particles. For instance, within the slave boson method 17 , the original fermionic X operator is decoupled as X = 9 f, where band f are usual boson and fermion operators, respectively. The second diculty can be dealt with by using a non-perturbative technique (which we will use in the present paper) based on a large-N expansion, where N is the number of electronic degrees of freedom per site and 1 N is assumed to be a small parameter. At one-quarter lling (which is the main interest in this paper), we expect the large-N approach to be a good approximation. This has been shown in the overdoped regime of high-Tc cuprates 18.

Ham iltorian (1) has been treated via large-N in a slave boson representation in Ref. 17 for V = 0, and in the context of quarter-led layered organic superconductors ($V \in 0$) in Ref. 4. Here, we concentrate on the dynam ical

properties of H am iltonian (1), using the recently developed large-N expansion¹⁹. This method is based on a path integral representation of the H ubbard X -operators which is written in term sofG rassmann and usual bosonic variables associated with ferm i-like and boson-like operators, respectively. In doing this, additional constraints are needed to make these eld variables behave as H ubbard operators (satisfying their associated algebra), as they should. A lthough this may seem a great complication in the theory, in fact it avoids introducing any decoupling scheme of the original H ubbard operators, as in slave boson representations. For completeness we will summarize the framework used in the diagram matic expansion developed in Ref. [19].

Our starting point is the partition function Z written in the Euclidean form

$$Z = DX_{i} \times X_{i}^{00} + X_{i} \times X_{i} = 1 \times X_{i}^{0} \times X_{i}^{00}$$

$$Z = (sdetM_{AB})_{i}^{\frac{1}{2}} \exp(dL_{E}(X;X-)) : (5)$$

The Euclidean Lagrangian $L_{\rm E}$ (X ; X-) in (5) is

$$L_{E} (X; X_{-}) = \frac{1}{2} \frac{X}{i} \frac{(X_{-i}^{0} X_{i}^{0} + X_{-i}^{0} X_{i}^{0})}{X_{i}^{00}} + H (X) :$$
 (6)

It is worth noting at this point that the path integral representation of the partition function 5, looks dierent to that usually found in other solid state problem s. The measure of the integral contains additional constraints as well as a superdeterm inant, (sdetM $_{AB}$) $_{i}^{\frac{1}{2}}$. Also the kinetic term of the Lagrangian (6) is non-polynomial. The determinant reads

(sdetM_{AB})
$$_{i}^{\frac{1}{2}} = 1 = \frac{1}{(X^{00})^{2}};$$
 (7)

and is form ed by all the constraints of the theory. Note that (sdetM $_{AB}$) $_{i}^{\frac{1}{2}}$ is not proportional to (X^{00})², because the theory is constrained in a supersymmetric sense where boson and ferm ion determinants must be treated in dierent ways (see Ref[19] form ore details about the path integral formalism for Hubbard operators). The constraints appearing in the theory are necessary in order to recover the correct algebra of the original Hubbard operators. In Eq. (10) we show how to treat this determinant through the use of a large-N expansion.

We now discuss the main steps needed to introduce a large-N expansion of the partition function (5). First, we integrate over the boson variables X using the second -function in (5). We extend the spin index = , to a new index p running from 1 to N . In order to get a nite theory in the N ! 1 limit, we re-scale the hopping t_{ij} to t_{ij} =N and V_{ij} to V_{ij} =N . In doing so, note that t_{ij} =N (rather than t_{pj}), should be tited to band structure calculations. The completeness condition is enforced by exponentiating: $X_i^{00} + \sum_{p} X_i^{pp} = N = 2$, with the help of Lagrangian multipliers i. We write the boson elds in terms of static mean-eld values, $(r_0; 0)$ and dynamic uctuations

$$X_{i}^{00} = N r_{0} (1 + R_{i})$$

 $i = 0 + i;$ (8)

and, nally, we make the following change of variables

$$f_{ip}^{+} = p \frac{1}{N r_{o}} X_{i}^{p0}$$

$$f_{ip} = p \frac{1}{N r_{o}} X_{i}^{0p}; \qquad (9)$$

where f_{ip}^+ and f_{ip} are G rassm ann variables.

Introducing the above change of variables (Eq. (8) and Eq. (9)) into Eq. (6) and, after expanding the denominator appearing in (6), we arrive at the following elective Lagrangian:

$$\begin{split} L_{eff} &= \frac{1}{2} \frac{X^{N}}{i_{p}} f_{ip}^{+} + f_{ip}^{+} f_{ip} & (1 - R_{i} + R_{i}^{2}) \\ &+ X^{N} \\ &+ t_{ij} r_{o} f_{ip}^{+} f_{jp} + X^{N} \\ &+ v_{ij} r_{o}^{2} f_{ip}^{+} f_{jp} + V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o}^{2} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{j} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{i} R_{ij} \\ &+ v_{ij} r_{o} f_{ip}^{2} f_{ip} & V_{ij} r_{o}^{2} R_{ij} R_{ij} \\ &+ v_{ij} r_{o} f_{ij} r_{o} R_{ij} R_{ij} R_{ij} \\ &+ v_{ij} r_{o} f_{ij} r_{o} R_{ij} R_{ij} R_{ij} R_{ij} \\ &+ v_{ij} r_{o} R_{ij} R_{$$

where $_0$ has been absorbed in the chem ical potential ! $_0$ and all constant and linear terms in the elds have been dropped. The path integral representation of (sdetM $_{AB}$) $^{\frac{1}{2}}$, written in terms of the N-component boson ghost elds, $_0^{20}$ Z $_{p}$, leads to the last term of Lagrangian (10). Note that all the complications arising from the Hubbard algebra have been translated to an elective theory of ferm ions interacting with bosons. Indeed, the interaction terms appearing in the elective lagrangian (10) are generated solely by the Hubbard algebra (apart from the no double occupancy constraint) and are not present in the original ham iltonian (3), which is quadratic in the Hubbard operators.

In the above expansion we have only retained the rst non-trivial terms that couple the ferm ionic and bosonic modes. In order to have a system atic scheme to classify and deal with these interaction terms we introduce a set of Feynman rules in powers of $1=N^{-19}$. These will help us to determ ine, for instance, that the terms retained in the ective Lagrangian (10) correspond to expanding through 0 (1=N) in the large-N expansion. The Feynman rules needed to carry out this project can be summarized as follows:

(i) Propagators: We associate with the two component $X^a = (R;)$ boson eld, the bare propagator D $_0$

$$D_{(0)ab}^{1}(q; n) = N \qquad \begin{array}{c} 4V r_0^2 (\cos(q_x) + \cos(q_y)) & r_0 \\ r_0 & 0 \end{array} \tag{11}$$

which is represented by a dashed line in Fig. 1 connecting two generic components a and b. q and $_n$ are the momentum and the M atsubara frequency of the boson elds, respectively.

The bare propagator of the N -com ponent ferm ion $% \left(t\right) =0$ eld $\left(t\right) =0$ reads

$$G_{(0)pp^{0}}(k;!_{n}) = \frac{pp^{0}}{i!_{n} (!_{k})}$$
(12)

which is represented by a solid line in Fig.1 connecting two generic components p and p^0 . The electron dispersion relation appearing in Eq. (12) is the one associated with the original fermions renormalized by the interaction: $\mathbf{r}_k = 2t\epsilon_0 (\cos(k_x) + \cos(k_y))$, with t the hopping between nearest neighbors sites on the square lattice. The quantities k and \mathbf{r}_n are the momentum and the fermionic M atsubara frequencies of the fermion eld, respectively.

W e associate with the N -component bare ghost eld Z_p the propagator

$$D_{pp^0} = pp^0$$
 (13)

which is represented by a dotted line in Fig. 1 connecting two generic components p and p'.

(ii) Vertices: The expressions of the di erent three-leg and four-leg vertices are

$$\sum_{a}^{pp^{0}} = \frac{\dot{1}}{2} (! + !^{0}) + ; 1 \qquad pp^{0}$$
 (14)

representing the interaction between two ferm ions and one boson (see Fig.1(a));

representing the interaction between two ferm ions and two bosons (see Fig. 1 (b));

$$a_{pp^0} = (1)(pp^0; 0);$$
 (16)

representing the interaction between two ghosts and one boson (Fig. 1 (c)); and

$$_{pp^{0}}^{ab} = (1) \quad _{0}^{1} \quad _{0}^{0} \quad _{pp^{0}}^{0}$$
(17)

representing the interaction between two bosons and two ghosts (Fig. 1(d)). Each vertex conserves momentum and energy, as it should.

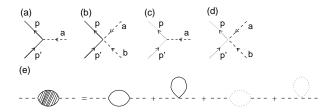


FIG. 1: Feynm an diagram s in the large-N expansion of the Hubbard operator theory. Solid lines represent ferm ions which are related to the electrons. D ashed lines represent bosons which are related to charge uctuations. D otted lines represent ghosts which are not physical but related to the constraints appearing in the theory which enforce that ferm ions satisfy the Hubbard operator algebra. (a) to (d) show the types of vertex which occur up to order $0 \ (1=N)$. (a) is the vertex between two ferm ions and one boson. (b) is the vertex between two ferm ions and two bosons. (c) is the vertex between two ghosts and one boson. (d) shows the vertex between two bosons and two ghosts. (e) represents the sum of all one-loop diagrams contributing to the irreducible boson self-energy which is of $0 \ (1=N)$.

In the lowest order of the expansion N = 1, we have the original ferm ions renormalized by the interaction, $\mathbf{v}_k = 2tr_0(\cos(k_x) + \cos(k_y))$. For a given value of , \mathbf{r}_0 must be determined self-consistently. For instance, \mathbf{r}_0 is equal to =2 (where is the hole doping away from half-lling) from (8) and the completeness condition (4).

The path integral (5) is written in terms of the original X-operators without having to introduce slave particles. Eq.(5) is analogue to the path integral used for the H eisenberg m odel where, using SU (2) coherent states, the measure can be written 21 in terms of the spin S. There is, however, an extra price we have to pay if we work with the original Hubbard operators. For instance, we need to introduce a new constraint (the second delta function in Eq. (5)) and the determinant (sdetM $_{\rm AB}$) of the matrix formed by the constraints appearing in the theory 19 . In spite of these "apparent" complications our formulation is very exible in calculating the physical quantities of interest, as it will be shown below.

In sum mary, we have developed a diagram matic technique appropriate for a large-N expansion along the lines of the large-N expansion developed in quantum eld theory. Hence, from the order of the propagators and vertices, we can determ ine the order of the diagram contribution.

To conclude this section we make contact with closely related approaches such as slave boson formulations. In contrast to slave boson theories: (a) G reens functions are calculated in terms of the original Hubbard operators, (b) ferm ions, f_{ip} , appearing in the theory are proportional to the Ferm i-like X -operator X op (see (8)) to all orders in the 1=N expansion; not only to leading order 22 , (c) as our path integral is written in terms of X -operators we do not need to introduce a priori any decoupling scheme, and (d) r_0 is the mean value of X 00 which is a real eld associated with the number of holes (see Eq. (8)) and not with the number of holes. At leading order (N ! 1 or O (1)) and V = 0, our formalism is equivalent to slave boson approaches. However, at the next to leading order (O (1=N)), (which is necessary to calculate one-electron properties such as the electron self energy (k;!) and the electron spectral function A (k;!)), the two formulations do not coincide. The di erences between the two formulations are not yet completely established. Our theory has the signicant advantage that it does not require the introduction of gauge elds like in slave boson approaches. Hence, through order O (1=N) we do not need to take care of gauge uctuations nor Bose condensation (note that Eq. 8 does not mean Bose condensation). This is in portant because for the doped Hubbard model the gauge uctuations are known to signicantly change the physics 23 . C areful numerical work will determ ine the in provements of the present approach with respect to slave boson formulations.

III. DYNAM ICAL PROPERTIES OF THE METALLIC PHASE CLOSE TO THE CHARGE ORDERING TRANSITION

In this section, we analyze using large-N and Lanczos techniques the in uence of the charge ordering transition on the dynam ical properties of the normal metallic phase.

A. Charge response

The dynamical electronic density-density response function can be written in terms of Hubbard operators. We dene the retarded density-density, Green's function as

$$D_{ij}^{*}() = \frac{1}{N} \times T \times_{i}^{pp}() \times_{j}^{qq}(0) > :$$
 (18)

From $_{q}^{P}X_{i}^{qq}=N$ =2 X_{i}^{00} and (8) we nd, after Fourier transform ing,

$$D^{*}(q;_{n}) = N_{\frac{1}{2}}^{2} D_{RR}(q;_{n});$$
(19)

Here D $_{RR}$ (q; $_n$) is the (R; R) component of the boson propagator. This is the only physical component of the boson propagator and encodes the charge uctuations occurring in the system. O ther components of the boson propagator such as the (;R) or (;) contain the nonphysical eld which are introduced to enforce the no double-occupancy constraint. Unlike in slave boson theories, the (R; R) component used here is associated directly with the charge and not with a ctitious bosonic eld (holon).

Through O (1=N) the boson propagator consists of the bare boson propagator D $_{(0)}$ (which is of order O (1=N)) renorm alized by a RPA-type series of electronic bubbles. The irreducible boson self-energy components, $_{ab}$, are obtained (through order 1=N) from the sum mation of all the contributions corresponding to the one-loop diagrams shown in Fig. 1 (e).

The last two diagrams appearing in Fig. 1(e) involving ghost elds are very important. It is possible to show that these two diagrams exactly cancel the in nities, due to the frequency dependence of our vertices, of the two rst diagrams appearing in Fig. 1(e). Ghost elds interact only with the boson elds as can be seen from Fig. 1(c) and Fig. 1(d). Sum marizing, the only role of ghost elds, through order 1=N, is to cancel in nities in the boson self-energy ab arising from the frequency dependence of our vertices (14) and (15).

U sing our Feynman rules, we can now write out explicitly each of the components of the boson self-energy ab

$$R_{RR} (q; n) = \frac{N}{N_s} \frac{1}{4} \sum_{k} [2 n_F ("_k) ("_{k+q} "_k) + ("_{k+q} + "_k)^2 \frac{[n_F ("_{k+q}) n_F ("_k)]}{i_n + "_{k+q} "_k};$$
(20)

$$R_{R}(q; n) = \frac{N}{N_{s}} \frac{1}{2} \frac{X}{k} (\mathbf{v}_{k+q} + \mathbf{v}_{k})$$

$$\frac{[n_{F}(\mathbf{v}_{k+q}) n_{F}(\mathbf{v}_{k})]}{[n_{F} + \mathbf{v}_{k+q}]}$$
(21)

and,

$$(q;_{n}) = \frac{N}{N_{s}} \times \frac{[n_{F} ("_{k+q}) n_{F} ("_{k})]}{i_{n} + "_{k+q} "_{k}} :$$
 (22)

where N $_{\rm S}$ is the number of sites of the system .

From Dyson's equation and ab the dressed components of the boson propagator, Dab, can be found:

$$(D_{ab})^{1} = (D_{(0)ab})^{1}$$
 ab (23)

D_{ab} m ay contain collective excitations such as zero sound²².

In order to look at charge ordering instabilities induced by the intersite C oulom b interaction, V , we have calculated the static charge susceptibility D' (q; $_{\rm n}$ = 0) for di erent q vectors on the B rillouin zone (B Z). At one-quarter lling (= 0.5) the corresponding chemical potential is = 0.360t in the limit N ! 1 . We not that the static susceptibility diverges at the wavevector $q_{\rm c}$ = (;) for V = V $_{\rm c}$ 0.65t signalling the instability to a checkerboard charge density wave (CDW). The value of $V_{\rm c}$ is slightly smaller than the one previously found using slave bosons 4 , $V_{\rm c}$ 0.69t. This is because of the decoupling of the electron operators introduced within slave bosons to treat the

intersite interaction term , $V n_i n_j$ which is not needed (due to the use of Hubbard operators) in the present large-N approach. For comparison, recent exact diagonalization calculations 11 give a critical value for the metal-insulator transition driven by V at about V_c 2t for U=20t. The large dierence in V_c between large-N and Lanczos diagonalization calculations can be attributed to the strong renormalization of the bare band (given by $v_0=20t$) which appears in large-N approaches at 0 (1). Introducing higher order terms in the 1-N -expansion may give larger values of V_c , in closer agreement with Lanczos calculations.

In Fig. 2 we show the evolution of $\,$ ImD $\,$ (q_c ;) as the system is driven close to the charge ordering instability, V < V_c, for the wavevector: q_c = (;). The intersite C oulomb repulsion softens the plasm on mode at q_c which appears for U ! 1 and V = 0 and, at the same time, increases its weight. At wavevectors far from q_c the plasm on mode shows up as a peak located at frequencies of about twhich carries small weight and is barely in uenced by V. Because the mode at (;) is plasm on-like it can be detected, in principle, with electron energy loss scattering (EELS)^{24} or inelastic X-ray scattering^{25}. With EELS one is able to obtain information on the electronic properties of the system at a given energy and wavevector, so that, for instance, the dispersion relation of the mode can be mapped out. A more appropriate way of detecting the plasm on-like mode is by using inelastic X-ray scattering, which provides a direct probe of the dynamical charge correlation function and has been successfully applied to one- and two-dimensional Mott-Hubbard system s²⁵.

In order to compare with large-N we compute, with Lanczos diagonalization, the spectral decomposition of the charge correlation function

$$C (q;) = \lim_{m} \mathfrak{N}_{q} \mathfrak{Dif} ((E_{m} E_{0}))$$
 (24)

where N $_{\rm q}$ = 1 = $^{\rm p}_{\rm i}$ e $^{\rm iqR_{\, 1}}$ ($c_{\rm i}^{\rm t}$ $c_{\rm i}$ in $^{\rm t}$ $c_{\rm i}$ i). E $_{\rm m}$ and E $_{\rm 0}$ denote the excited and ground state energies of the system , respectively. L is the number of sites in the cluster. Note that C (q;) can be compared to $_{\rm imD}$ (q $_{\rm c}$;) as they have equivalent de nitions. Of course, attention must be paid to the fact that we are comparing calculations of the charge susceptibility on an in nite system with calculations on a L = 16 cluster. Indeed, we note that C (q $_{\rm c}$;) is in rather good agreement with $_{\rm imD}$ (q $_{\rm c}$;) (see Fig. 2), both displaying similar softening and increase in amplitude of the plasm on mode at (;) close to the charge ordering transition.

The imaginary part of the charge correlation close to the charge ordering wavevector: $q \cdot q_c$ can be ted to the following RPA form 26

$$ImD^{\circ}(q;) = A \frac{1}{2 + \frac{1}{2}}$$
 (25)

where $!_q = !_0 + C$ (q q_c)², where A and C are constants. $!_0$ gives the position of the peak appearing in the charge correlation function at (;) for di erent V's and goes to zero as V! V_c, measuring the proximity of the system to the charge ordering transition (see inset of Fig. 2). We note that the overall behavior of the charge susceptibility is analogous to the one of the spin susceptibility in nearly antiferrom agnetic metals^{27,28}.

B. Spectral densities

In order to calculate spectral densities, we set discuss the evaluation of the self-energy corrections to the bare ferm ion propagator (12), which occur at 0 (1=N). Using our Feynman rules there are two diagrams, shown in Fig. 3 (a), contributing to the self-energy to 0 (1=N). The analytical expression for these two diagrams reads:

$$pp = \begin{pmatrix} X & pp^0 \\ p^0 \mathcal{P}^0 \mathcal{P}^0$$

where integration over internal momenta and sum over Matsubara frequencies is assumed.

U sing the spectral representation for the boson $\,$ elds, D $_{ab}$, the imaginary part of the self-energy $\,$ Im $\,$ can be obtained

$$\text{Im } (k;!) = \frac{1}{N_s} \sum_{q}^{X} f_{\overline{q}}^{1} \text{Im } (D_{RR} (q;! | ||_{k_q})) (||_{k_q} + 2 + !)^{2}$$

$$+ \text{Im } (D_R (q;! ||_{k_q})) (||_{k_q} + 2 + !)$$

$$+ \text{Im } (D (q;! ||_{k_q})) g(n_B (! ||_{k_q}) + n_F (||_{k_q}))$$

$$(27)$$

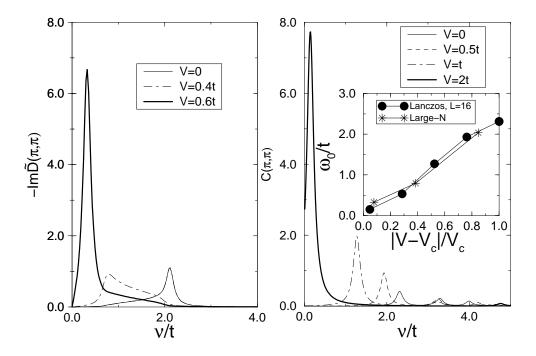


FIG. 2: The softening of the plasm on-like mode at the wavevector $q_c = ($;) as the system is driven closer to the checkerboard charge ordering transition. The frequency dependence of the charge correlation function is shown for several di erent values of V=t. The right and left panel show results obtained using Lanczos diagonalization on L = 16 site clusters (U = 20t) and large-N theory, respectively. A Lorentzian broadening of = 0:1t is used in the calculations. Only for wavevectors close to or at (;), the softening of the plasm on mode is observed as a consequence of the proximity of the system to a checkerboard charge ordering transition. Calculations of dynamical properties using large-N theory at O(1=N), which couples the electrons to the short range charge uctuations associated with this transition, and Lanczos diagonalization, suggest that this plasm on mode is responsible for the 'unconventional' behavior of dynamical properties. The inset compares the position of the plasm on peak at (;) computed from Lanczos and large-N approaches.

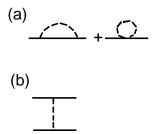


FIG. 3: (a) Contributions to the electron self-energy, (k;!), through O (1=N), in the Hubbard operator theory. The rst diagram contains two three-leg vertices as the ones shown in Fig. 1(a) and the second one is formed with one four-leg vertex as shown in Fig. 1(b). (b) Contribution to the elective interaction between quasiparticles, V_{eff} , through O (1=N). This interaction is used in the present work to analyze superconducting instabilities of the Fermi liquid induced by the charge uctuations appearing close to a checkerboard charge ordering transition induce by V.

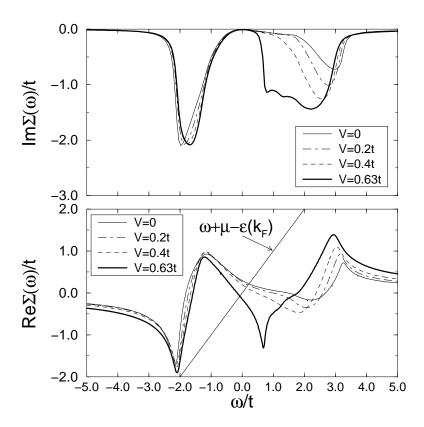


FIG. 4: Evolution of the real and imaginary parts of the self-energy of an electron at the Ferm is urface as the system is driven close to the checkerboard charge ordering transition from large-N theory. The amplitude of the self-energy is enhanced at frequencies between t and 3t due to the enhancement of uctuations associated with (;) short range charge ordering. The behavior of the self-energy leads to an enhancement of spectral weight in the spectral density (see Figs. 5) and an incoherent band in the DOS (see Fig. 8) between ! = t and 3t as we approach the charge ordering transition. The intersection of the curve of Re (!) versus ! with ! + (k) determines the quasi-particle peaks in the electronic spectral function.

Note that this self-energy is the one associated with the propagator G(k;!) of the Hubbard X-operators. In contrast, in slave-boson approaches a convolution of the ferm ion and boson operators is needed in order to recover the actual electronic self-energy²².

Fig. 4 shows the behavior of Im (k;!) with increasing V for a wavevector on the Ferm isurface: k = (1204;1204) (we have used = 0:1t in the analytical continuation). As we approach $V = V_c$, both the imaginary and real parts of the self-energy (which from Eq. (27) involves a sum over the full BZ) are enhanced in the positive range of frequencies to 3t due to the scattering of the electrons of the checkerboard charge uctuations. Performing a K ram ers-K roning transformation on Im, we can obtain the real part of the self-energy, Re, which is also plotted in Fig. 4.

From Im and Re, we can compute the electron spectral function A $(k;!) = \frac{1}{2} \text{Im } G(k;!)$ as

$$A (k;!) = \frac{1}{(! + "_k Re (k;!))^2 + Im (k;!)^2}$$
 (28)

In Fig. 5 we show the spectral function obtained from large-N theory, for an electron at k=(0;0); (1204;1204); (;), for dierent values of V! V_c . The spectral density of an electron at the Fermi surface displays a quasiparticle peak characteristic of a Fermi liquid at! = . The rest of spectral weight that is left is incoherent.

The quasiparticle weight, Z_k , evaluated at the Ferm i surface is dened as

$$Z_k = (1 - \frac{\theta R e (k;!)}{\theta!})^{-1} \dot{J}_{=0}$$
: (29)

In the inset of Fig. 5 we observe how a gradual suppression of Z_k occurs as the charge ordering transition is approached. This can be compared to the suppression of the D rude weight found in Lanczos calculations 11 , which is also evident in the spectral function plotted in Figs. 6 and 7. Spectral weight is transferred from the quasiparticle peak to the range of energies between t 3t, as V tends to V_c due to the scattering of the electrons of the charge uctuations associated with short range checkerboard charge ordering. The modes close to (;) give the strongest

contribution to the scattering. The apparent peak around ! = 2t should not be interpreted as a quasiparticle peak but as the lower Hubbard band²⁹ associated with the on-site Coulomb repulsion U.

The behavior of the spectral density shown in Fig. 5 can be now understood from the evolution of the real part of the self-energy shown in Fig. 4. The scattering of electrons from the strong charge uctuations at (;) wavevectors involves large frequencies. This leads to an enhancement of the real part of the self-energy at large frequencies which, in turn, produces an increase of spectral weight at large and intermediate energies. This behavior is analogous to the one found in metals in the presence of short range spin uctuations 30 . Unlike in the case of nearly antiferrom agnetic metals, no new poles induced by the interaction arise. This is because at quarter-lling no two points of the Ferm i surface are connected by the scattering wavevector $q_c = (;)$, and therefore the electrons is weaker than spin uctuations in systems close to half-lling.

In order to test the validity of the large-N approach we have also computed the spectral densities from Lanczos diagonalization of nite clusters 31

$$A^{(+)}(k;!) = \int_{m}^{X} m ; N_{e} + 1 \dot{p}_{k}^{+} \mathcal{D}; N_{e} \dot{i} \mathcal{D}^{2} (! (E_{m}(N_{e} + 1) E_{0}(N_{e})))$$
(30)

for adding and electron to the system $\,$ w ith N $_{\rm e}$ electrons and

$$A^{()}(k;!) = \sum_{m}^{X} j_{m}; N_{e} \quad j_{m}; N_{e} \quad j_{m}; N_{e} i_{m}^{2} \quad (! + (E_{m}(N_{e} \quad 1) \quad E_{0}(N_{e})))$$
(31)

for rem oving an electron from the N $_e$ electron system . E $_m$ and E $_0$ denote the excited and ground state energies of the system and c_k^y = 1= $\stackrel{\cdot}{L}^{}_{j}e^{ik\,R\,_j}c_j^y$. In Figs. 6 and 7 we plot the evolution of the spectral densities calculated with Lanczos techniques for wavevectors

In Figs. 6 and 7 we plot the evolution of the spectral densities calculated with Lanczos techniques for wavevectors at k = (0;0); (=2;0); (=2;=2) and (;) for different values of V=t. At k = (0;0) two sharp peaks are clearly distinguished already for V=0. One of them is the quasiparticle peak and we associate the lower one with the lower Hubbard band due to the presence of the U. For the nearest wavevectors to the Fermi energy: k = (=2;0) and (=2;=2), we indicate the lower ent of incoherent spectral weight at in its frequencies as the charge ordering transition is approached.

Finally, the total density of states (DOS) can be computed from

$$N(!) = \frac{1}{L} X (A()) (k;!) + A() (k;!)$$
 (32)

In Fig. 8 we compare the evolution of the DOS, N (!), for increasing V=t, calculated with both Lanczos at U ! 1 and large-N.

From Lanczos calculations we observe (left panel of Fig. 8) for V=0 a band at about 3t, a quasiparticle band at situated at != and a band running from t to 5t. As V=t is increased the weight of the quasiparticle peak is reduced and weight between 2t and 5t is gradually enhanced. A lso a suppression of spectral weight at low frequencies occurs as a precusor e ect before the charge ordering transition takes place. This general behavior is in qualitative agreement with large-N calculations. Indeed, an incoherent band at negative frequencies of about 2t, associated with the lower Hubbard band, a suppression of states close to the Fermi energy and an overall enhancement of spectra between t and 3t occurs (see right panel of Fig. 8). However, we note that the pseudogap appearing within large-N is less pronounced than in Lanczos calculations. This can be attributed to nite size e ects appearing in small cluster Lanczos calculations.

C. Optical conductivity

It is interesting to analyze the behavior of the optical conductivity as the system is driven through the charge ordering transition. Using Lanczos diagonalisation we have computed

$$(!) = D \quad (!) + \frac{e^2}{L} \frac{X}{E_n} \frac{j_n j_k j_{ij}}{E_n} \quad (! \quad E_n + E_0);$$
(33)

where j_x is the current in the x-direction, E_0 the ground state energy and E_n the excited energies of the system . e is the electron charge and the D rude weight is denoted by D .

The following sum $ru e^{32}$ is satis ed by (!),

$$(!)d! = \frac{e^2}{4L} < 0 \text{ fr } \text{ j}0 > :$$
 (34)

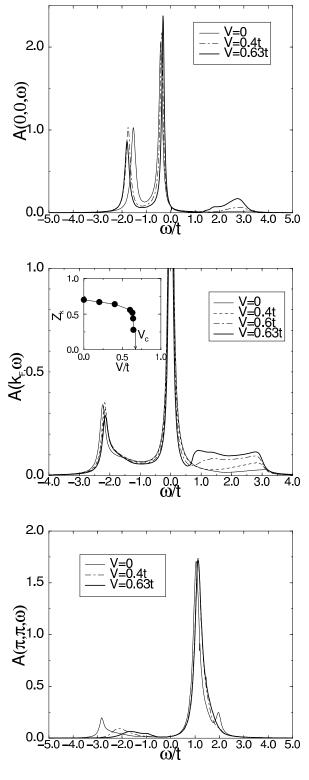


FIG.5: Evolution of quasiparticle spectral density of states computed from large-N theory of an electron at the wavevectors k=(0,0), $(k_F\,;k_F\,)$, and $(\;;\;)$. Close to the charge ordering transition spectral weight is transferred from the quasiparticle peak to low and intermediate frequencies. The quasiparticle weight at the Fermienergy, Z_k , is rapidly suppressed (see inset) as the charge ordering transition is approached V ! V_c . The results presented here can be compared with A (k;!) computed from Lanczos shown in Fig. 6 and 7.

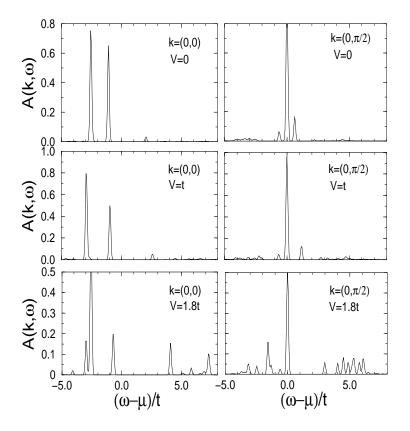


FIG. 6: Evolution of quasiparticle spectral density of states, A (k;!), at k=(0;0) and (0;=2), computed from Lanczos diagonalisation on a L=16 cluster for an extended Hubbard model at quarter-lling. The on-site C oulomb repulsion is taken to be U=20t and a broadening of the delta peaks, =0:1t is used. As the system approaches the metal-insulator transition, an enhancement of spectral weight at nite frequencies and a suppression of the weight at the Fermi energy takes place. At k=(0;0), the two sharp peaks are associated with the lower Hubbard band and the quasiparticle peak. An overall qualitative agreement with the results from large-N theory is found (see Fig. 5).

where T is the kinetic energy operator, which is the rst term in the Hamiltonian (1).

The optical conductivity is plotted in Fig. 9, for increasing values of the ratio V=t and $xed\ U=20t$. At V=0 we not a D rude peak and a broad m id-infrared band centered at about 3t. As V=t is increased the m id-infrared band is enhanced and a well-de ned feature builds up at the lower edge of the m id-infrared band, at frequencies of about 2t. Also an incoherent band present at larger energies of the order of U (not shown for clarity) is gradually suppressed and its associated weight transferred to the m id-infrared band as V is increased. From the behavior of spectral densities and DOS shown in Figs. 5-8, we attribute the enhancement of optical weight observed in the mid-infrared range to an increase in the incoherent excitations carried by each quasiparticle as a result of charge uctuations associated with short range checkerboard charge ordering. From the behavior of the spectral densities, A $\{k; l\}$ shown in Fig. 6 and 7 and assuming that a lowest order diagram (neglecting vertex corrections) is enough to compute the optical conductivity we would attribute the low energy feature to transitions between the incoherent band carried by each quasiparticle and the quasiparticle peak situated at the Ferminenergy. This interpretation is plausible if one notes that the low energy feature observed in Fig. 9 m oves together with the broad band as V=t is increased. Similar results would be obtained from large-N theory evaluating the bubble Feynm and diagram for the optical conductivity, as the spectral densities obtained are similar to the ones obtained from Lanczos diagonalization.

IV. CONNECTION TO EXPERIMENTAL RESULTS

Recent experiments with Ram an scattering 33 and optical conductivity measurements 34 on the insulating salt - (BDT-TTP) $_2$ Cu(NCS) $_2$ nd that the checkerboard charge ordered state discussed in this paper is indeed the ground state. This gives experimental support to the model discussed here. A discussion of other possible orderings within more complicated models can be found in the work by Seo 35 and C lay, M azum dar, and C ampbell 36 .

W e review now the experim ents on resistivity m easurem ents on several quarter-lled organics, and make contact

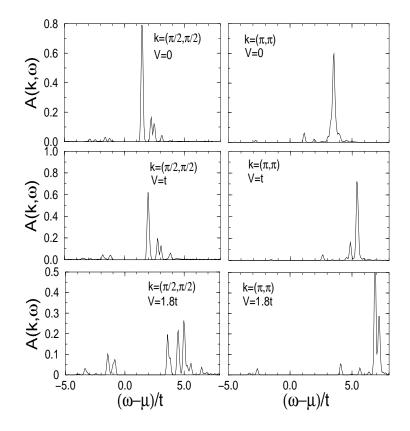


FIG. 7: Evolution of quasiparticle spectral density of states, A (k;!), at k = (=2; =2), and (;), computed from Lanczos diagonalization on a L = 16 site cluster for an extended Hubbard model at quarter-lling. The on-site Coulomb repulsion is taken to be U = 20t and a Lorentzian broadening of the delta peaks, = 0.1t is used.

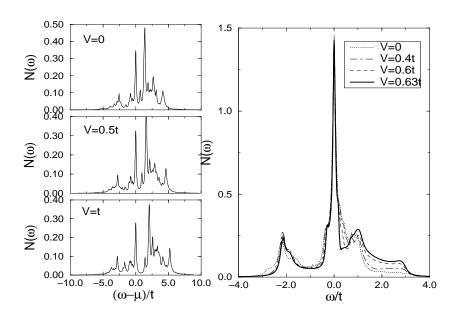


FIG.8: Evolution of the total density of states (DOS) as the charge-ordering transition is approached from the metallic phase. The left and right panels show results from exact diagonalisation on a 16 site lattice with U ! 1 and large-N approaches, respectively. (The critical value of V is V_c 2t and 0:65t, respectively). A Lorentzian broadening of = 0:1t has been introduced in the exact diagonalisation calculations, to aid comparison with the large N results. As the intersite Coulomb repulsion V is increased, the density of states close to the Fermienergy is gradually suppressed indicating the proximity to the charge ordering transition. At the same time spectral weight is enhanced for frequencies in the range t to 3t in the large-N. The peak at -2t is an incoherent band associated with the lower Hubbard band. An overall qualitative agreement between Lanczos and large-N calculations is found.

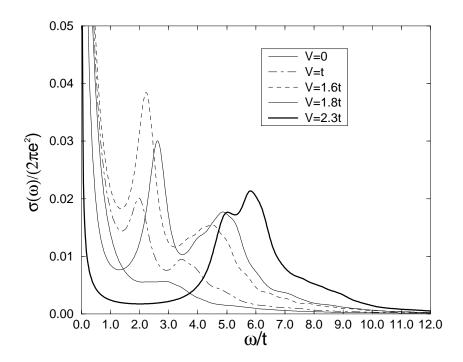


FIG. 9: Evolution of the optical conductivity computed from Lanczos diagonalisation as the system is driven through the metal-insulator transition. The calculation is performed on a L=16 site cluster, U=20t and dierent V, with a Lorentzian broadening of =0.4t. Enhancement of optical weight at low frequencies is found as V is increased. The broad band situated at about 3V (for large V=t) is due to incoherent transitions between dierent sites induced by the intersite C oulomb repulsion. We interpret the low energy feature appearing at about 2t as a consequence of transitions between the incoherent band and the quasiparticle peak found in the spectral densities A(k;!) for wavevectors on the Fermi surface.

with the predictions of the large-N approach presented.

From the in aginary part of the self-energy (Eq. (27)) we can obtain the behavior of the inverse of the lifetine of the quasiparticles, $1=(T)=2\text{Im}\ (k_F;0)$ with temperature as shown in Fig. 10. From this plot we obtain a temperature scale, T=0.22t, at which 1=(T), changes from T^2 to T behavior. The temperature scale dened by T decreases only slightly as we approach the charge ordering transition remaining nite as V! V_c (through O(1=N)). This is in contrast to dynamical mean—eld approaches where a similar low temperature scale is suppressed as the M ott-Hubbard metal insulator (driven by U instead of V) is approached T0. Hence, Fermi liquid behavior is found below this temperature scale even close to the charge ordering transition occurring at V0. Presum ably, higher order corrections in the T1-T1 expansion may suppress the region where the system behaves as a Fermi liquid as V1. V_c 1. Future work should focus in understanding this issue better.

We have also computed the temperature dependence of the elective mass defined as: $m=m=1=Z_k$ (T), evaluated at the Fermi surface and is shown in Fig. 11. Large-N theory predicts an increase of m=m as the temperature is raised for V! V_c . This means that the system becomes more incoherent as the temperature is increased. Interestingly this behavior is also found in the Hubbard model in the limit of in nite dimensions close to the Mott metal-insulator transition 38 . However in that case the system is close to a metal-insulator transition which takes place between two non-ordered phases, in contrast to the charge ordering transition discussed here. At V=0 the elective mass is temperature independent as one would expect from a weakly interacting system. At the lowest temperatures we obtain enhanced elective masses in the range 1.3 to 2, for V=t, varying from 0 to 0.63.

In Fig. 12 we show optical conductivity data of $-(BEDT-TTF)_2CsCo(SCN)_4$ along the a-direction³⁹ at T=15 K. This salt is metallic down to temperatures of about 10 K. At this temperature a charge ordering transition to an insulating phase takes place. The observed optical conductivity displays a band situated at 12 eV, a mid-infrared band appearing at frequencies of about 0.25 eV, and a feature appearing at low frequencies of about 0.13 eV. In the same gure we present a comparison of our exact diagonalization calculations of the optical conductivity performed on a 16 site cluster, U=t=20 and V=t=1.2 where we have set the hopping energy scale to t=0.061eV, so that

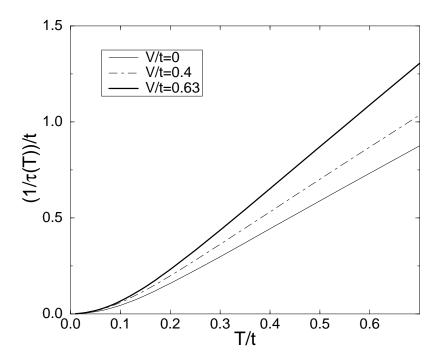


FIG. 10: Tem perature dependence of the scattering rate 1= (T) = 2Im (k $_{\text{F}}$;! = 0). This scattering, which is due to charge uctuations, increases as the charge-ordering transition is approached. As the tem perature increases above about T 0.22t, 1= (T) changes from a T 2 dependence to a linear behavior in T. This tem perature scale depends only slightly with V, so that large-N theory (through O (1=N)) predicts Ferm i liquid behavior close to the charge ordering transition at tem peratures below T.

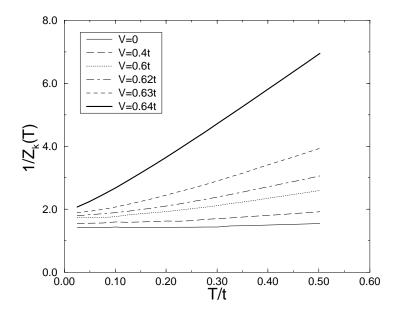


FIG. 11: Tem perature dependence of the e ective m ass of an electron on the Ferm i surface, m = $1=Z_k$ (T), as obtained from large-N theory through O (1=N). As the system is driven closer to the charge ordering transition a stronger increase of the e ective m ass with T is found.

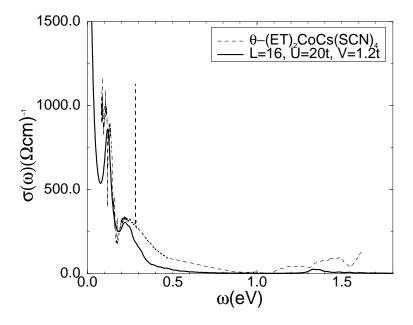


FIG. 12: Comparison of the optical conductivity computed from Lanczos diagonalisation on L = 16 site clusters with experim ental results 39 for the metallic salt $-(BEDT-TTF)_2CsCo(SCN)_4$. For the exact diagonalization results we have chosen: U = 20t and V = 12t. In order to t the data we chose t = 0.061 eV, which can be compared to values from Huckel band structure calculations 40 . The lattice parameters for $-(BEDT-TTF)_2CsCo(SCN)_4$ are a = 9.804A, c = 4.873A and $V_{cell} = 4V_{mol} = 2074A^3$, where V_{cell} and V_{mol} are the volumes per unit cell and per molecule, respectively. The broad band at about 0.25 eV and the low energy feature at 0.13 eV can be explained from short range charge ordering induced by the intersite Coulomb repulsion V. This behavior is characteristic of several quarter—led layered metallic salts which undergo a metal-insulator transition at su ciently low temperatures.

we associate the m id-infrared band observed experim entally with the one from exact diagonalization calculations. In this way, we recover the main features appearing in the experim ental data, including the incoherent high-frequency feature and the feature appearing at low frequencies. This behavior is commonly observed in metallic—salts close to the metal-insulator transition and from Fig. 12 we notice that the low energy feature can be misinterpreted as being part of the D rude peak. Caution is in order when comparing our results with experimental data as shown in Fig. 12 because some features like the dip appearing at about 0.17 eV have been interpreted in $-(ET)_2RbZn$ (SCN)₄ (where a structural transition takes place with lowering temperature) as being caused by the coupling to vibronic modes of the ET molecules³⁹. More experimental and theoretical work is needed to understand this issue better.

V. SUPERCONDUCTIVITY

In the present section we discuss the possibility of having superconductivity close to the charge ordering transition induced by the short-range charge uctuations which appear in the metallic phase. Here we extend the discussion presented in Ref.[6] and provide full details of the calculations. We also consider the binding energy of holes using a Lanczos calculation.

A. Large-N: pairing sym metry

W ithin the large-N approach, superconductivity is possible at 0 (1=N). As we have already seen at 0 (1), our approach describes quasiparticle excitations with renormalized masses. Interaction between these quasiparticles can appear at the next-to-leading order of 0 (1=N). The electric interaction between electrons are those represented diagram matically in Fig.3 (b); only the three-leg vertex shown in Fig.1 (a) contributes to the electric interaction through order 0 (1=N).

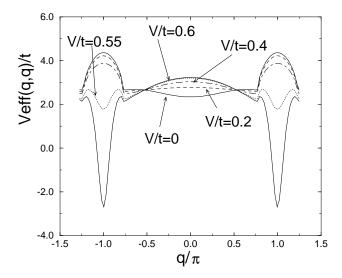


FIG. 13: Behavior of the elective potential between quasiparticles, $V_{\rm eff}$ (q_x;q_y), as a function of momenta for increasing V=t values along the q_x = q_y = q direction. As V=t! (V=t)_c, the elective potential becomes negative at the (;) points, becoming singular at the transition to the checkerboard charge ordered insulator. It is the momentum dependence of the potential shown here which leads to the d_{xy} symmetry of the Cooper pairs. This calculation was done using the large-N approach through O (1=N).

U sing the Feynm an rules introduced above (see Fig. 3 (b)), the interaction between the quasiparticles (k; k 0) reads

(k
$$k^{0}; !_{n}$$
 $!_{n^{0}}) = [^{2}D_{RR} (k k^{0}; !_{n} !_{n^{0}}) + 2 D_{R} (k k^{0}; !_{n} !_{n^{0}}) + D (k k^{0}; !_{n} !_{n^{0}})]$ (35)

where is the chemical potential and D $_{ab}$ are the components of the boson propagator which are obtained from Dyson's equation (23).

In Fig. 13 we plot the dependence of V_{eff} (q = k k^0) (q;!! 0)=(=2), that is the static lim it of the elective interaction mediating the possible pairing between the quasiparticles. This clearly shows the development of the singularity due to checkerboard charge ordering at the (;) wavevectors. We note that the elective interaction, obtained from Eq.(35), which is valid on the whole Brillouin zone, coincides only with the one obtained using slave boson approaches, when it is evaluated at the Fermi surface.

In weak coupling, we use this elective potential to compute the elective couplings in the dilerent pairing channels or irreducible representations of the order parameter, i (i = $(d_{x^2 y^2}; d_{xy}; s)$). In this way we project out the interaction with a certain symmetry. The critical temperature, T_c , can then be estimated from: $T_{ci} = 1:13!_0 \exp(1-j_i)$, where t_0 is a suitable cuto frequency and t_0 are the elective couplings with dilerent symmetries. These are defined as t_0 and t_0 are the elective couplings with dilerent symmetries.

$$i = \frac{1}{(2)^{2}} \frac{R}{(dk = jv_{k})} \frac{R}{(dk = jv_{k})} \frac{R}{(dk = jv_{k})} \frac{R}{(gk = jv_{k})} \frac{R}{g_{i}(k)^{2}} \frac{R}{(gk = jv_{k})} \frac{R}{g_{i}(k)^{2}}$$
(36)

where the functions: $g_i(k)$, encode the di erent pairing symmetries, and v_k are the quasiparticle velocities at the Fermi surface. The integrations are restricted to the Fermi surface. i measures the strength of the interaction between electrons at the Fermi surface in a given symmetry channel i. If i > 0, electrons are repelled. Hence, superconductivity is only possible when i < 0. In Fig. 14 we plot the dependence of the electrons couplings in the possible symmetry channels with V=t.

We observe that near the charge ordering instability but still in the metallic phase: $V < V_{\rm C}$, the coupling in the $d_{\rm xy}$ channel, $d_{\rm xy}$, become attractive whereas other couplings become more repulsive. However, we note that the couplings are rather small. This implies that critical temperatures are expected to be small. Similar conclusions have been reached with large-N treatments of the U-in nite Hubbard model at V=0 close to half-lling 42 . Exact diagonalisation results also lead to similar conclusions 31 . Although the eigenvalues are small, our results are nontrivial and show a tendency of the model to Cooper pairing in the $d_{\rm xy}$ channel. Intuitively one would think that superconductivity is

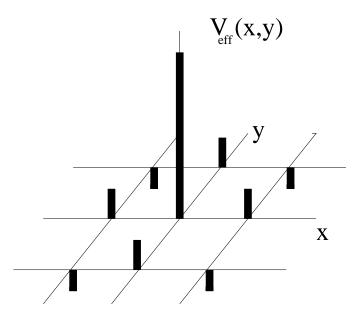


FIG.14: Dependence of the elective couplings with V=t as defined in Eq. (36) in the different symmetry channels. Close to the charge ordering transition pairing in the d_{xy} channel becomes favorable while other possible pairing symmetries are repulsive for any V.

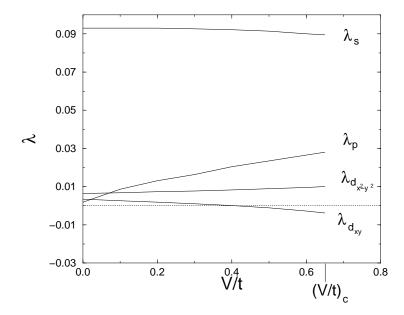


FIG. 15: Schem attic plot showing the Fourier transform of the elective potential, $V_{\rm eff}$ ($q_{\rm x}$; $q_{\rm y}$) for V=t (V=t)_c to real space. $V_{\rm eff}$ (x;y) is understood as follows. A quasiparticle is placed at the origin. For instance, if another quasiparticle is placed also at the origin there is a large repulsion between them due to the large on-site Coulomb repulsion. This is shown by the large positive vertical bar at the origin. At neighboring sites (along the x, and y-directions) the elective potential between quasiparticles is also positive, i.e., repulsive. However, at the next-nearest-neighbor sites (along the diagonals of the lattice), the potential becomes attractive. This leads to d_{xy} pairing of the quasiparticles.

less and less favorable when increasing V, due to the repulsion between electrons in neighboring sites. Contrary to this intuition we not that short range charge uctuations can mediate pairing close to V_c .

In Fig. 13 we observe that as we increase V, the elective interaction becomes more repulsive at small momentum transfer. On the other hand, they become more attractive for momenta transfer close to (;). That d_{xy} symmetry is favored can be more clearly understood from Fig. 15 which shows a schematic plot of the Fourier transform of $V_{\rm eff}$ (q) (see Fig. 13). One sees that the potential is negative for an electron placed at the nearest neighbor diagonal sites of the lattice while it is positive along the x and y-directions. This is in contrast to the elective potential resulting

from spin-uctuations which show the opposite behavior. This can be understood from previous calculations on a 3-D extended Hubbard model close to half-lling within RPA performed by Scalapino, Loh and Hirsch⁴¹, which found that the elective potential for charge uctuations has a negative divergence at (;) as the transition is approached whereas for spin uctuations it is positively diverging⁴¹. Due to the fact that the Fermi surface at one-quarter lling is small (no two points in the Fermi surface are connected by the (;)) wavevector), the interaction is less elective in inducing pairing as compared to spin uctuations in nearly antiferrom agnetic metals close to half-lling.

The T_c values shown in the phase diagram in Ref. [6] are larger than the values that would be obtained for $T_{cd_{xy}}$ from the BCS equation. In Ref. [6] T_c (for each V) was taken to be the temperature below which the coupling d_{xy} becomes negative. Such a calculation is indicative for superconductivity. However, the appropriate way to obtain T_c is by solving the associated E liashberg gap equation.

In conclusion, in the present study we nd tendencies to superconductivity in the d_{xy} channel mediated by short range charge uctuations which appear in the metallic phase close to the charge ordering instability.

B. Lanczos diagonalization: binding energies

We have computed the binding energy of two holes for dierent values of V=t and U=20t on dierent clusters. The binding energy of two holes for L=16 is de ned as 43,44,45

$$E_B$$
 (2 holes) = (E (6) E (8)) 2 (E (7) E (8)); (37)

where E (N $_{\rm e}$) is the energy of the system with N $_{\rm e}$ electrons.

In Fig. 16 we plot the binding energy for dierent values of V. Initially, as we increase V, the binding energy becomes more positive. This corresponds to the weak coupling regime where one naively expects that V keeps the quasiparticles farther apart. Further increasing of V closer to the m etal-insulator transition but still in the m etallic phase leads to a negative binding energy of two holes. From nite size scaling of the binding energy of clusters up to L = 20 sites, we not that this happens at about V 1:6t. This nite size scaling is shown in the inset of Fig. 16 for values of V close to the m etal-insulator transition. Rem arkably, the binding energy of two holes changes only slightly in the range of values t < V < 2t when going from L = 16 to L = 20. However, in the region $V > V_c = 2t$, the results change signi cantly as we increase the size of the cluster from L = 16 to 20, and the binding energy would eventually extrapolate to a positive value in the therm odynam ic lim it. It is interesting that this region corresponds to the insulating phase found earlier 1 from Lanczos calculations of the D rude weight. An interpretation of our results can be made based on previous works 43,44 which studied the binding energy of an extended Hubbard model of the high-T c superconductors close to half-lling as a function of V. As V is increased charge uctuations associated with checkerboard charge ordering increase and the quasiparticles existing at small V gradually dress up with a cloud of checkerboard charge excitations. This leaves signatures in the one-electron dynamical properties as explained in previous sections. Further increasing of V leads to pairing between the quasiparticles mediated by the strong charge uctuations⁴⁴. Increasing V even further drives the system into the insulating phase.

Sum m arizing, a de nitive conclusion about superconductivity cannot be m ade from our results. However, it is remarkable that both large-N and Lanczos diagonalization calculations show a similar tendency to pairing of quasiparticles in the metallic phase close to the charge ordering transition. Large-N theory singles out the d_{xy} sym metry as the preferred pairing channel of the quasiparticles. This sym metry is consistent with the checkerboard charge order present in the region where the Lanczos pairing energy becomes negative.

VI. CONCLUSIONS

In sum mary, using a combination of large-N and Lanczos techniques we have explored the dynam ical properties of the extended Hubbard model at quarter—lling. This is motivated by its relevance to a large class of superconducting layered organic molecular crystals. The correlation functions computed from large-N theory and Lanczos techniques are found to be in good agreement. Indeed, close to the charge ordering transition driven by the intersite Coulomb repulsion, V, several features are found: (i) The quasiparticle weight, Z_k , is rapidly suppressed near the charge ordering transition. (ii) Spectral density is enhanced at frequencies ranging from t to 3t, which is also rejected in the optical conductivity. (iii) From the computation of the electron scattering rate weight and Fermi liquid behavior up to T, where T does not depend strongly on V. For T > T the scattering rate behaves linearly with T. (iv) From large-N calculations we not that superconductivity with d_{xy} symmetry is favored close to the charge ordering transition. Exact diagonalization calculations of the binding energy of two holes are consistent with this possibility.

G iven our prediction of unconventional superconductivity in the and 0 m olecular crystals it is desirable that m ore m easurem ents be m ade to test for this. The only evidence so far com es from a m easurem ent of the tem perature

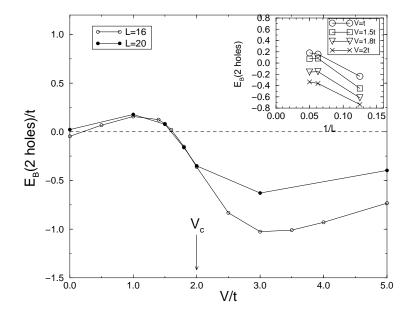


FIG. 16: B inding energy of two holes for di erent values of V and U = 20t from exact diagonalisation calculations on L = 16 and L = 20 clusters. C lose to the charge ordering transition, in the range, V > 1:6t, binding of two holes become s favorable. V_c denotes the value of V at which the metal-insulator transition is estimated to take place from Lanczos calculations of the D rude weight. Note that the value of V at which E_B (2 holes) becomes negative is robust against increasing the cluster size from L = 16 to L = 20. These results are consistent with large-N calculations supporting the possibility of pair form ation close to the charge ordering transition.

dependence of the London penetration depth of $\,^{00}$ -(BEDT-TTF) $_2$ SF $_5$ CH $_2$ CF $_2$ SO $_3$. It was found to go like T 3 at low tem peratures. This is inconsistent with an s-wave state, but also deviates signi cantly from the linear tem perature dependence expected for a d-wave state. On the other hand, the tem perature dependence of the heat capacity is consistent with s-wave pairing. Electronic Ram an scattering could be used to investigate the sym metry of the superconducting order parameter. For d_{xy} sym metry, Ram an scattering in the superconducting state should show, at low frequencies, either!,! 3 , or! behavior for B $_{1g}$, B $_{2g}$ and, A $_{1g}$ sym metries, respectively 48 .

An important issue to be resolved concerns the role of spin uctuations in the quarter-led materials. To rst order in 1/N, the large-N approach used here does not take spin uctuations into account. And M easurements of the nuclear magnetic resonance relaxation rate and K night shift should be done in the metallic phase for the relevant superconductors. If the spin uctuations are not important there should be no enhancement of the K orringa ratio. This is in contrast to the large enhancements seen in $-(BEDT-TTF)_2X$ superconductors which are close to an antiferrom agnetic M ott insulator.

One way to theoretically investigate the role of the antiferrom agnetic spin—uctuations that m ay be present near the charge-ordering transition is as follows. Well into the insulating charge ordered phase (i.e., for V t) it is known that there is an antiferrom agnetic exchange interaction $J^0 = 4t^4 = 9V^3$ that acts along the diagonals of the square lattice⁴. Some remnant of this elect will still be present when there is short-range charge order. This could be modelled by considering at J^0 V model where the J^0 acts only along the diagonals. This model could be studied by the same large-N method used previously to study a large family of the square J^0 V models that the superexchange, acting along the vertical and horizontal lattice directions, produced J^0 0 superconductivity. Blased on that work we anticipate that the elect of the superexchange, which now acts in directions rotated by 45 degrees, will be to produce J^0 1 superconductivity. Hence, it is possible that charge and spin—uctuations work together co-operatively to produce J^0 1 pairing.

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